

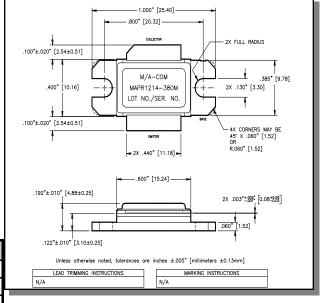
Production 02 Feb 2012

### Radar Pulsed Power Transistor 380 WATTS, 1.2-1.4 GHz, 150us Pulse, 10% DUTY

# Outline Drawing

#### Features

- NPN Silicon Microwave Power Transistors
- Common Base Configuration
- Broadband Class C Operation
- High Efficiency Interdigitated Geometry
- Diffused Emitter Ballasting Resistors
- Gold Metallization System
- Internal Input and Output Impedance Matching
- Hermetic Metal/Ceramic Package
- RoHS Compliant



#### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V <sub>CES</sub>	88	V
Emitter-Base Voltage	V <sub>EBO</sub>	3.0	V
Collector Current (Peak)	lc	23.9	А
Power Dissipation @ +25°C	P <sub>TOT</sub>	700	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	ΤJ	200	°C

#### Electrical Specifications: T<sub>c</sub> = 25 ± 5°C (ROOM AMBIENT )

Parameter	Test Conditions	Frequency	Symbol	Min	Мах	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA		BV <sub>CES</sub>	90	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 44V		I <sub>CES</sub>	-	10	mA
Thermal Resistance	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	R <sub>TH(JC)</sub>	-	0.25	°C/W
Output Power	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	Po	380	-	W
Power Gain	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	G <sub>P</sub>	8.8	-	dB
Gain Flatness	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	$\Delta G_P$		1	dB
Droop	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	Droop	-	0.6	dB
Collector Efficiency	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	ηc	45	-	%
Input Return Loss	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	RL	-	-9	dB
Load Mismatch Tolerance	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	2:1	-
Load Mismatch Stability	Vcc = 44V, Pin = 50W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

<sup>1</sup> 

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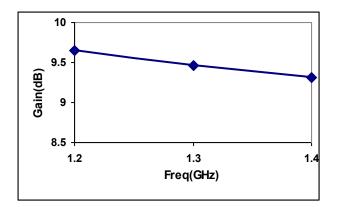
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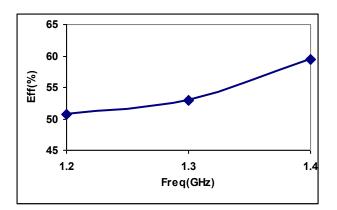
#### **Typical RF Performance**

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	∆Gain (dB)	Eff (%)	RL (dB)	Droop (dB)	VSWR-S 1.5:1	VSWR-T 2:01
1.2	50	458.5	9.65		50.75	-23.6	0.15	S	Р
1.3	50	436.8	9.46		52.88	-16.8	-0.02	S	Ρ
1.4	50	421.3	9.31	0.34	59.52	-15.2	-0.01	S	Р

Gain vs. Frequency



### **Collector Efficiency vs. Frequency**



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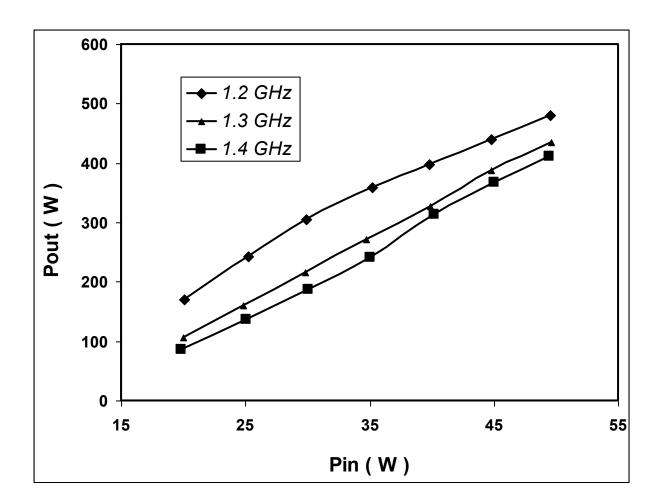
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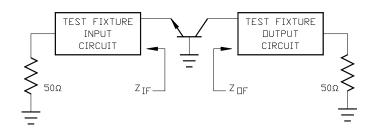
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RF Power Transfer Curve (Output Power Vs. Input Power)



#### **Broadband Test Fixture Impedance**

F (MHz)	<b>Ζ</b> <sub>IF</sub> (Ω)	<b>Ζ</b> <sub>OF</sub> (Ω)
1200	1.3 - j1.89	1.08 - j1.83
1300	1.43 - j1.28	1.08 - j1.24
1400	1.51 - j0.73	1.1 - j0.75



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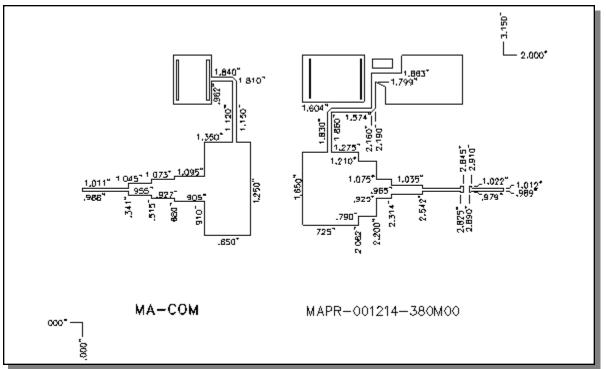
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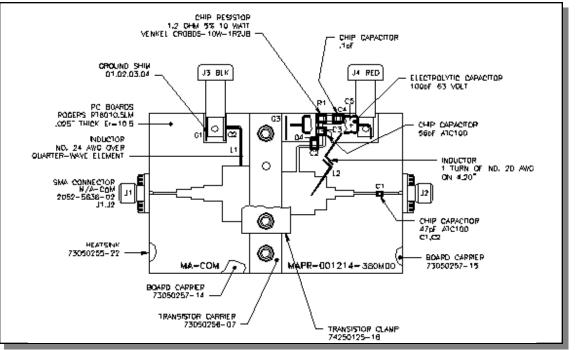
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### **Test Fixture Circuit Dimensions**



#### **Test Fixture Assembly**



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